

T-52-07.

IR2C34 4-Unit 320mA Transistor Array

■ Description

The IR2C34 is a 4-circuit driver IC, which is able to directly drive a load of 320mA with minute input current.

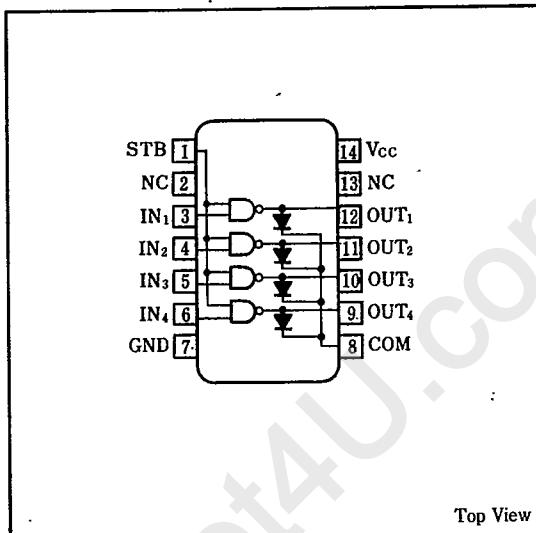
It is suited for driving printers, relays, LEDs and lamps. With a strobe input terminal provided, this transistor array allows all the circuits to stop interrupts without adding any external transistor.

The clamp diode for spike killer, being provided for each output, prevents the output transistor from being destroyed by reverse electromotive force.

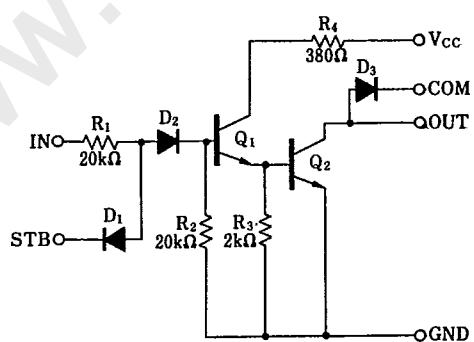
■ Features

1. Strobe terminal
2. Clamp diode
3. Output breakdown voltage $BV_{CEO}=20V$ (MAX.)
4. Output current $I_{OUT}=320mA$ (MAX.)
5. 14-pin dual-in-line package

■ Pin Connections



■ Equivalent Circuit



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IR2C34

Absolute Maximum Ratings

(Ta = -20°C ~ +75°C)

| Parameter | Symbol | Condition | Rating | Unit |
|-------------------------------|---------------------|-----------------------|------------|-------|
| Supply voltage | V _{CC} | | 10 | V |
| Output breakdown voltage | BV _{CBO} | | 20 | V |
| Output current | I _{OUT} | | 320 | mA |
| Input voltage | V _{IN} | | -25 ~ +20 | V |
| Strobe input voltage | V _{IN STB} | | 20 | V |
| Clamp diode reverse voltage | V _R | | 20 | V |
| Clamp diode forward current | I _F | | 320 | mA |
| Power dissipation | P _D | T _a ≤ 25°C | 1.14 | W |
| P _D derating ratio | ΔP _D /°C | T _a > 25°C | 11.4 | mW/°C |
| Operating temperature | T _{opr} | | -20 ~ +75 | °C |
| Storage temperature | T _{stg} | | -55 ~ +150 | °C |

Recommended Operating Conditions

(Ta = -20°C ~ +75°C)

| Parameter | Symbol | Condition | MIN. | TYP. | MAX. | Unit |
|-------------------------------|--------------------|--|------|------|------|------|
| Supply voltage | V _{CC} | | 3 | | 8 | V |
| Maximum output voltage | V _{CBO} | | | | 20 | V |
| Output current | I _{OUT} | V _{CC} =6.5V at 25% duty or less | | | 300 | mA |
| | | V _{CC} =6.5V at 65% duty or less | | | 150 | |
| Input "High" voltage | V _H | I _{OUT} =150mA | 5 | | | V |
| | | I _{OUT} =300mA | 7 | | | |
| Input "Low" voltage | V _L | I _{OUT} (Leak)=50 μA | | | 1 | V |
| Input "High" voltage (strobe) | V _{H STB} | | 2.4 | | | V |
| Input "Low" voltage (strobe) | V _{L STB} | | | | 0.2 | V |

Input/Output Logic

| IN | STB | OUT |
|----|-----|-----|
| L | L | H |
| H | L | H |
| L | H | H |
| H | H | L |

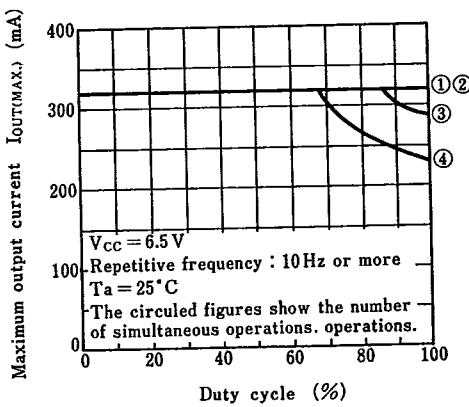
4-Unit 320mA Transistor Array

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(Ta = -20°C ~ +75°C)

Electrical Characteristics

| Parameter | Symbol | Condition | MIN. | TYP. | MAX. | Unit |
|--------------------------------|----------------------|--|------|------|------|------|
| Output breakdown voltage | BV _{CEO} | V _{CC} =8V, V _{IN} =18V, V _{IN STB} =0.2V, I _{OUT} =100μA | 20 | | | V |
| Output voltage at ON | V _{OUT ON1} | V _{IN} =7V V _{CC} =6.5V, I _{OUT} =300mA | | 0.6 | 1.0 | V |
| | V _{OUT ON2} | V _{IN STB} V _{CC} =6.5V, I _{OUT} =250mA | | 0.5 | 0.85 | V |
| | V _{OUT ON3} | =2.4V V _{CC} =3V, I _{OUT} =120mA | | 0.3 | 0.5 | V |
| Input current | I _{IN} | V _{CC} =8V, V _{IN} =18V, V _{IN STB} =2.4V | | 0.8 | 1.8 | mA |
| Input reverse leakage current | I _{IR} | V _{CC} =8V, V _{IN} =-25V | | -20 | | μA |
| Strobe input current | I _{IS} | V _{CC} =8V, V _{IN} =18V (All inputs), V _{IN STB} =0.2V | | -4 | | mA |
| Strobe reverse leakage current | I _{IS STB} | V _{CC} =8V, V _{IN} =0V, V _{IN STB} =20V | | | 20 | μA |
| Clamp diode forward voltage | V _F | I _F =320mA | | 1.4 | 2.4 | V |
| Clamp diode reverse voltage | V _R | I _R =100μA | 20 | | | V |
| Supply current | I _{CC} | V _{CC} =8V, V _{IN} =7V (All input), V _{IN STB} =2.4V | | | 130 | mA |
| DC current amplification | h _{FE} | V _{OUT} =4V, V _{CC} =6.5V, I _{OUT} =300mA, Ta=25°C | 1000 | | | |

**Electrical Characteristic Curves****Maximum output current****Duty cycle Characteristics (1)****Maximum output current****Duty cycle Characteristics (2)**